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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	196
Number of Logic Elements/Cells	466
Total RAM Bits	6272
Number of I/O	112
Number of Gates	10000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	144-TFBGA, CSPBGA
Supplier Device Package	144-LCSBGA (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcs10xl-4cs144c

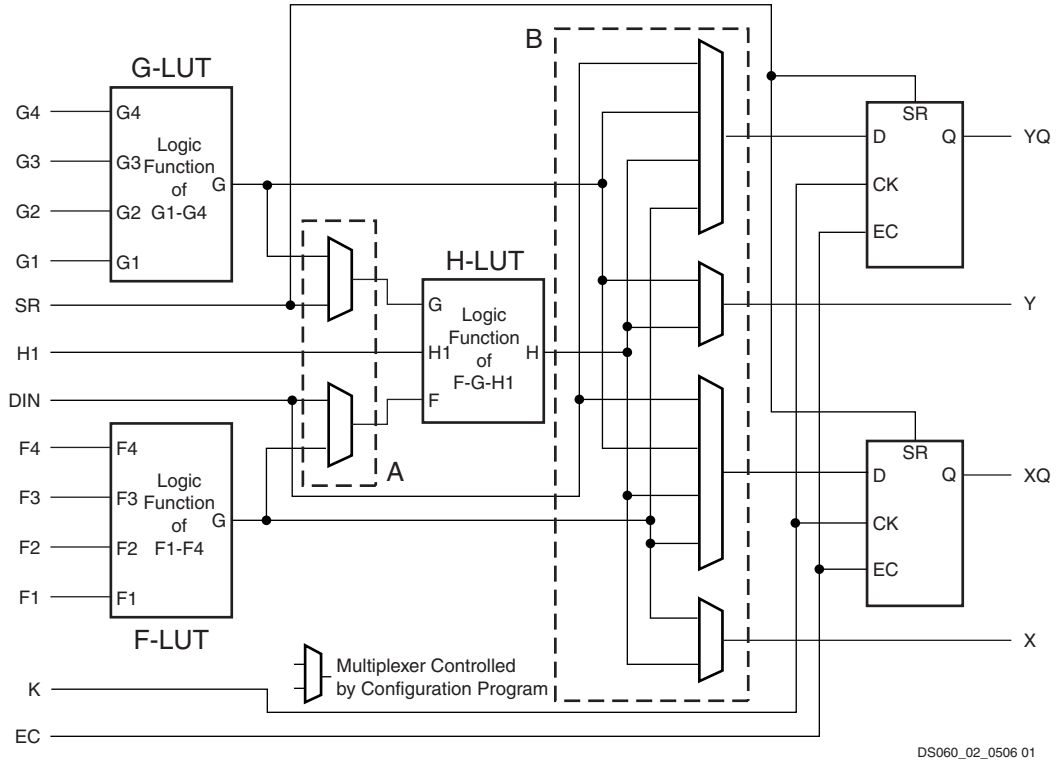


Figure 2: **Spartan/XL Simplified CLB Logic Diagram (some features not shown)**

A CLB can implement any of the following functions:

- Any function of up to four variables, plus any second function of up to four unrelated variables, plus any third function of up to three unrelated variables

  Note: When three separate functions are generated, one of the function outputs must be captured in a flip-flop internal to the CLB. Only two unregistered function generator outputs are available from the CLB.
- Any single function of five variables
- Any function of four variables together with some functions of six variables
- Some functions of up to nine variables.

Implementing wide functions in a single block reduces both the number of blocks required and the delay in the signal path, achieving both increased capacity and speed.

The versatility of the CLB function generators significantly improves system speed. In addition, the design-software tools can deal with each function generator independently. This flexibility improves cell usage.

Flip-Flops

Each CLB contains two flip-flops that can be used to register (store) the function generator outputs. The flip-flops and function generators can also be used independently (see Figure 2). The CLB input DIN can be used as a direct input to either of the two flip-flops. H1 can also drive either flip-flop via the H-LUT with a slight additional delay.

The two flip-flops have common clock (CK), clock enable (EC) and set/reset (SR) inputs. Internally both flip-flops are also controlled by a global initialization signal (GSR) which is described in detail in **Global Signals: GSR and GTS**, page 20.

Latches (Spartan-XL Family Only)

The Spartan-XL family CLB storage elements can also be configured as latches. The two latches have common clock (K) and clock enable (EC) inputs. Functionality of the storage element is described in Table 2.

- The 16 x 1 single-port configuration contains a RAM array with 16 locations, each one-bit wide. One 4-bit address decoder determines the RAM location for write and read operations. There is one input for writing data and one output for reading data, all at the selected address.
- The (16 x 1) x 2 single-port configuration combines two 16 x 1 single-port configurations (each according to the preceding description). There is one data input, one data output and one address decoder for each array. These arrays can be addressed independently.
- The 32 x 1 single-port configuration contains a RAM array with 32 locations, each one-bit wide. There is one data input, one data output, and one 5-bit address decoder.
- The dual-port mode 16 x 1 configuration contains a RAM array with 16 locations, each one-bit wide. There are two 4-bit address decoders, one for each port. One port consists of an input for writing and an output for reading, all at a selected address. The other port consists of one output for reading from an independently selected address.

The appropriate choice of RAM configuration mode for a given design should be based on timing and resource requirements, desired functionality, and the simplicity of the design process. Selection criteria include the following: Whereas the 32 x 1 single-port, the (16 x 1) x 2 single-port, and the 16 x 1 dual-port configurations each use one entire CLB, the 16 x 1 single-port configuration uses only one half of a CLB. Due to its simultaneous read/write capability, the dual-port RAM can transfer twice as much data as the single-port RAM, which permits only one data operation at any given time.

CLB memory configuration options are selected by using the appropriate library symbol in the design entry.

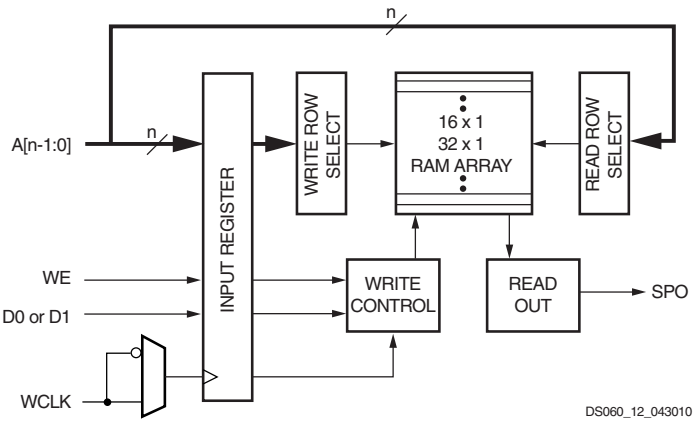
Single-Port Mode

There are three CLB memory configurations for the single-port RAM: 16 x 1, (16 x 1) x 2, and 32 x 1, the functional organization of which is shown in Figure 12.

The single-port RAM signals and the CLB signals (Figure 2, page 4) from which they are originally derived are shown in Table 9.

Table 9: **Single-Port RAM Signals**

RAM Signal	Function	CLB Signal
D0 or D1	Data In	DIN or H1
A[3:0]	Address	F[4:1] or G[4:1]
A4 (32 x 1 only)	Address	H1
WE	Write Enable	SR
WCLK	Clock	K
SPO	Single Port Out (Data Out)	F_{OUT} or G_{OUT}



Notes:
1. The (16 x 1) x 2 configuration combines two 16 x 1 single-port RAMs, each with its own independent address bus and data input. The same WE and WCLK signals are connected to both RAMs.
2. n = 4 for the 16 x 1 and (16 x 1) x 2 configurations. n = 5 for the 32 x 1 configuration.

Figure 12: **Logic Diagram for the Single-Port RAM**

Writing data to the single-port RAM is essentially the same as writing to a data register. It is an edge-triggered (synchronous) operation performed by applying an address to the A inputs and data to the D input during the active edge of WCLK while WE is High.

The timing relationships are shown in Figure 13. The High logic level on WE enables the input data register for writing. The active edge of WCLK latches the address, input data, and WE signals. Then, an internal write pulse is generated that loads the data into the memory cell.

CLB signals from which they are originally derived are shown in Table 10.

Table 10: **Dual-Port RAM Signals**

RAM Signal	Function	CLB Signal
D	Data In	DIN
A[3:0]	Read Address for Single-Port. Write Address for Single-Port and Dual-Port.	F[4:1]
DPRA[3:0]	Read Address for Dual-Port	G[4:1]
WE	Write Enable	SR
WCLK	Clock	K
SPO	Single Port Out (addressed by A[3:0])	F_{OUT}
DPO	Dual Port Out (addressed by DPRA[3:0])	G_{OUT}

The RAM16X1D primitive used to instantiate the dual-port RAM consists of an upper and a lower 16 x 1 memory array. The address port labeled A[3:0] supplies both the read and write addresses for the lower memory array, which behaves the same as the 16 x 1 single-port RAM array described previously. Single Port Out (SPO) serves as the data output for the lower memory. Therefore, SPO reflects the data at address A[3:0].

The other address port, labeled DPRA[3:0] for Dual Port Read Address, supplies the read address for the upper memory. The write address for this memory, however, comes from the address A[3:0]. Dual Port Out (DPO) serves as the data output for the upper memory. Therefore, DPO reflects the data at address DPRA[3:0].

By using A[3:0] for the write address and DPRA[3:0] for the read address, and reading only the DPO output, a FIFO that can read and write simultaneously is easily generated. The simultaneous read/write capability possible with the dual-port RAM can provide twice the effective data throughput of a single-port RAM alternating read and write operations.

The timing relationships for the dual-port RAM mode are shown in Figure 13.

Note that write operations to RAM are synchronous (edge-triggered); however, data access is asynchronous.

Initializing RAM at FPGA Configuration

Both RAM and ROM implementations in the Spartan/XL families are initialized during device configuration. The initial contents are defined via an INIT attribute or property attached to the RAM or ROM symbol, as described in the library guide. If not defined, all RAM contents are initialized to zeros, by default.

RAM initialization occurs only during device configuration. The RAM content is not affected by GSR.

More Information on Using RAM Inside CLBs

Three application notes are available from Xilinx that discuss synchronous (edge-triggered) RAM: *"Xilinx Edge-Triggered and Dual-Port RAM Capability," "Implementing FIFOs in Xilinx RAM,"* and *"Synchronous and Asynchronous FIFO Designs."* All three application notes apply to both the Spartan and the Spartan-XL families.

Fast Carry Logic

Each CLB F-LUT and G-LUT contains dedicated arithmetic logic for the fast generation of carry and borrow signals. This extra output is passed on to the function generator in the adjacent CLB. The carry chain is independent of normal routing resources. (See Figure 15.)

Dedicated fast carry logic greatly increases the efficiency and performance of adders, subtractors, accumulators, comparators and counters. It also opens the door to many new applications involving arithmetic operation, where the previous generations of FPGAs were not fast enough or too inefficient. High-speed address offset calculations in microprocessor or graphics systems, and high-speed addition in digital signal processing are two typical applications.

The two 4-input function generators can be configured as a 2-bit adder with built-in hidden carry that can be expanded to any length. This dedicated carry circuitry is so fast and efficient that conventional speed-up methods like carry generate/propagate are meaningless even at the 16-bit level, and of marginal benefit at the 32-bit level. This fast carry logic is one of the more significant features of the Spartan

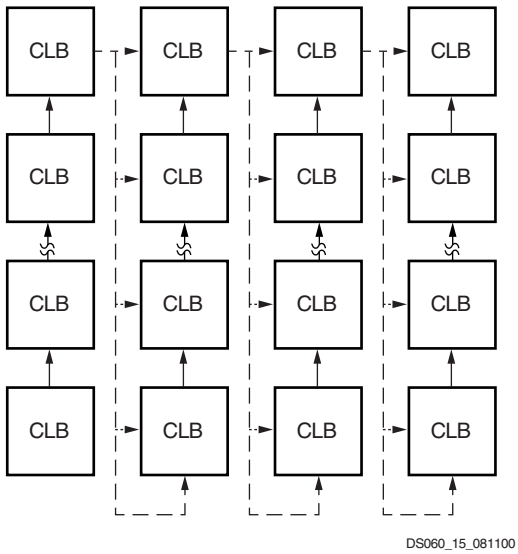


Figure 15: **Available Spartan/XL Carry Propagation Paths**

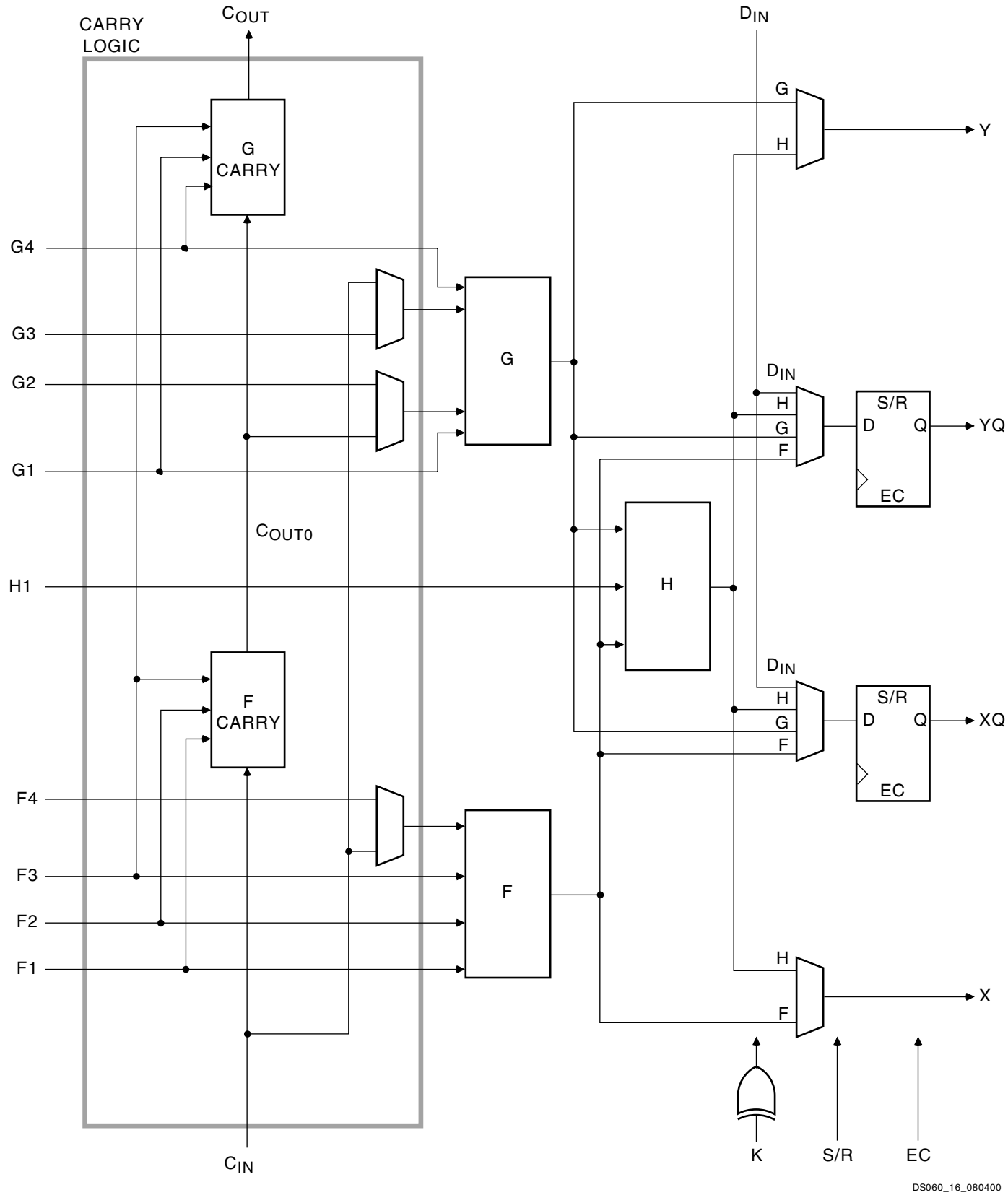


Figure 16: **Fast Carry Logic in Spartan/XL CLB**

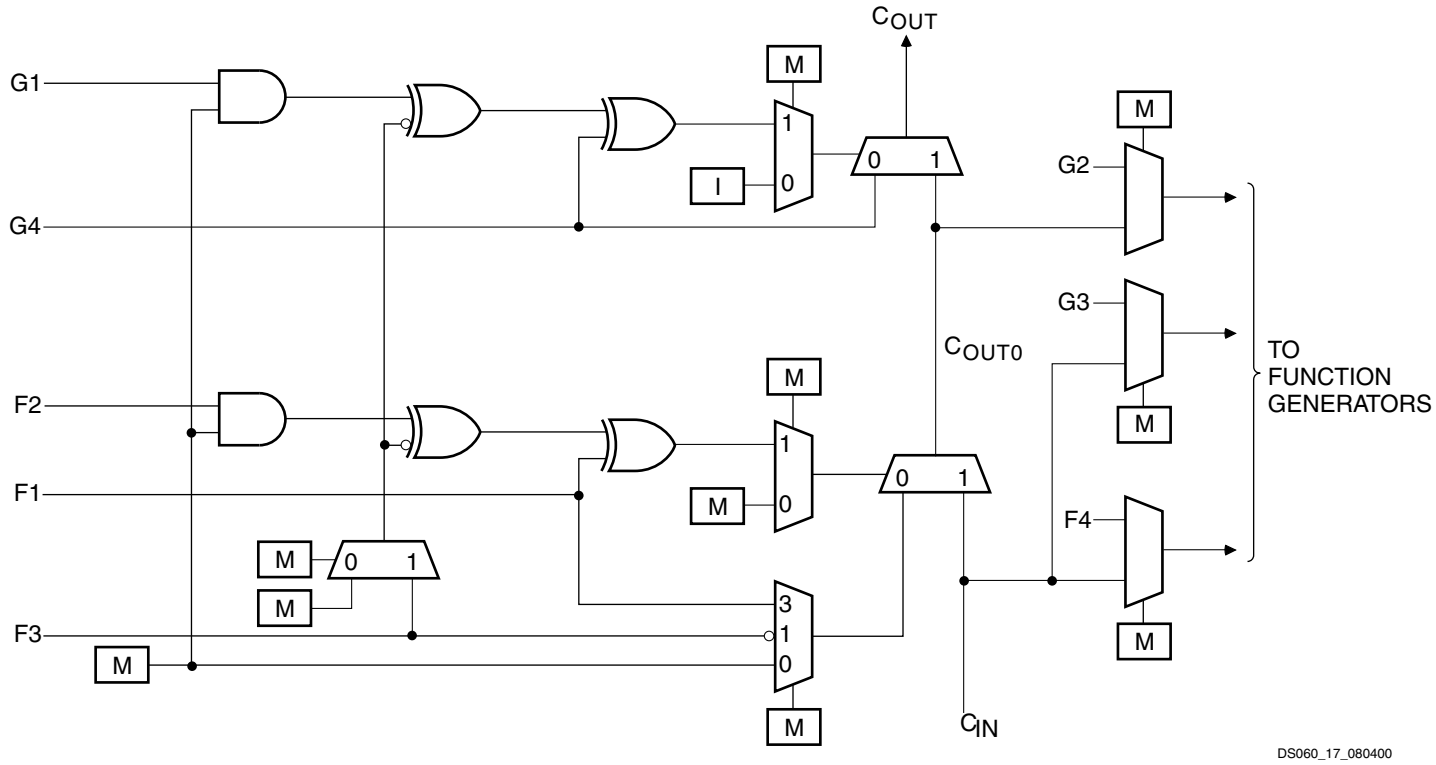


Figure 17: **Detail of Spartan/XL Dedicated Carry Logic**

3-State Long Line Drivers

A pair of 3-state buffers is associated with each CLB in the array. These 3-state buffers (BUFT) can be used to drive signals onto the nearest horizontal longlines above and below the CLB. They can therefore be used to implement multiplexed or bidirectional buses on the horizontal longlines, saving logic resources.

There is a weak keeper at each end of these two horizontal longlines. This circuit prevents undefined floating levels. However, it is overridden by any driver.

The buffer enable is an active High 3-state (i.e., an active Low enable), as shown in Table 11.

Three-State Buffer Example

Figure 18 shows how to use the 3-state buffers to implement a multiplexer. The selection is accomplished by the buffer 3-state signal.

Pay particular attention to the polarity of the T pin when using these buffers in a design. Active High 3-state (T) is identical to an active Low output enable, as shown in Table 11.

Table 11: **Three-State Buffer Functionality**

IN	T	OUT
X	1	Z
IN	0	IN

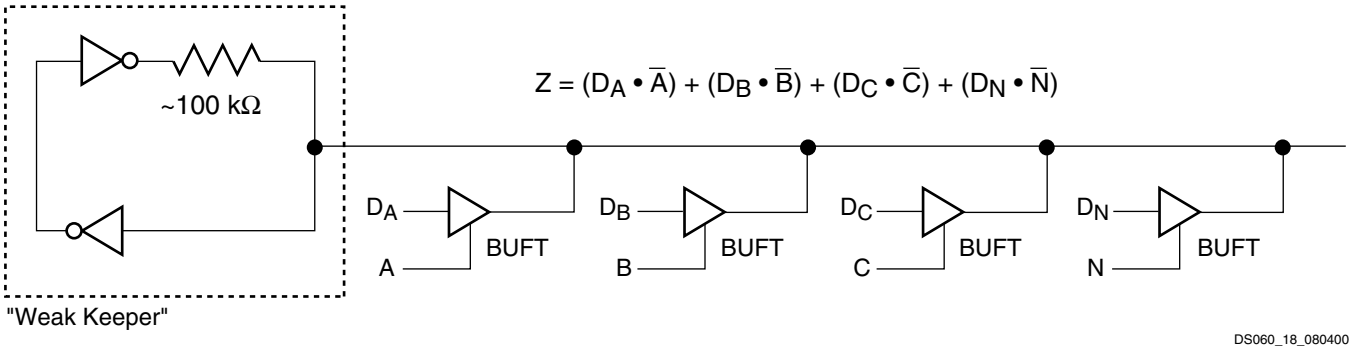


Figure 18: **3-state Buffers Implement a Multiplexer**

Table 12: **Boundary Scan Instructions**

Instruction			Test Selected	TDO Source	I/O Data Source
I2	I1	I0			
0	0	0	EXTEST	DR	DR
0	0	1	SAMPLE/ PRELOAD	DR	Pin/Logic
0	1	0	USER 1	BSCAN. TDO1	User Logic
0	1	1	USER 2	BSCAN. TDO2	User Logic
1	0	0	READBACK	Readback Data	Pin/Logic
1	0	1	CONFIGURE	DOUT	Disabled
1	1	0	IDCODE (Spartan-XL only)	IDCODE Register	-
1	1	1	BYPASS	Bypass Register	-

Bit Sequence

The bit sequence within each IOB is: In, Out, 3-state. The input-only pins contribute only the In bit to the boundary scan I/O data register, while the output-only pins contributes all three bits.

The first two bits in the I/O data register are TDO.T and TDO.O, which can be used for the capture of internal signals. The final bit is BSCANT.UPD, which can be used to drive an internal net. These locations are primarily used by Xilinx for internal testing.

From a cavity-up view of the chip (as shown in the FPGA Editor), starting in the upper right chip corner, the boundary scan data-register bits are ordered as shown in Figure 21. The device-specific pinout tables for the Spartan/XL devices include the boundary scan locations for each IOB pin.

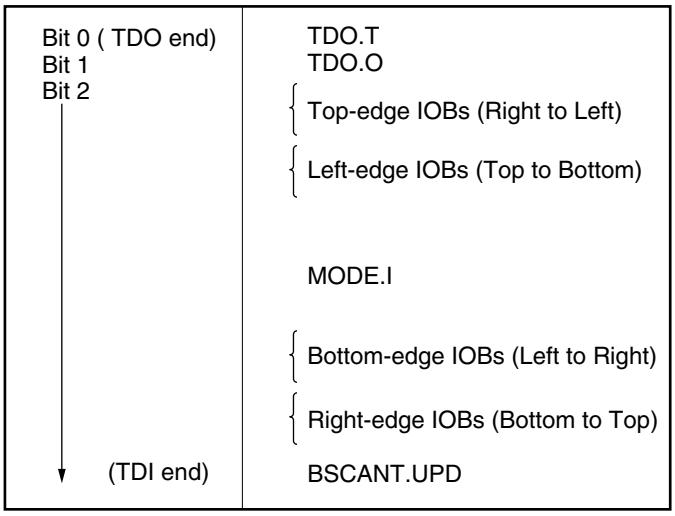


Figure 21: **Boundary Scan Bit Sequence**

BSDL (Boundary Scan Description Language) files for Spartan/XL devices are available on the Xilinx website in the File Download area. Note that the 5V Spartan devices and 3V Spartan-XL devices have different BSDL files.

Including Boundary Scan in a Design

If boundary scan is only to be used during configuration, no special elements need be included in the schematic or HDL code. In this case, the special boundary scan pins TDI, TMS, TCK and TDO can be used for user functions after configuration.

To indicate that boundary scan remain enabled after configuration, place the BSCAN library symbol and connect the TDI, TMS, TCK and TDO pad symbols to the appropriate pins, as shown in Figure 22.

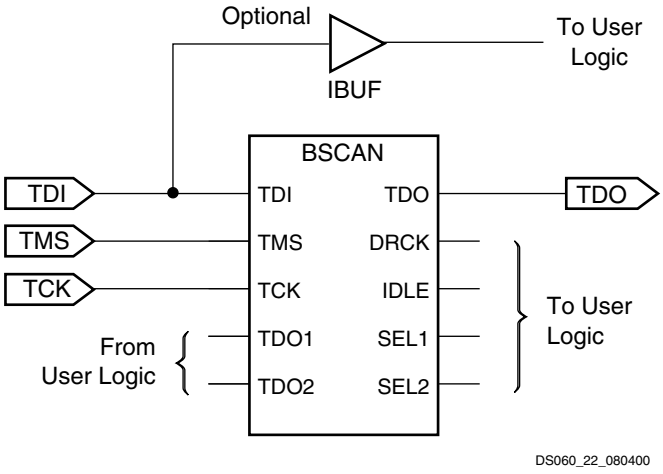


Figure 22: **Boundary Scan Example**

Table 17: **Spartan/XL Program Data**

Device	XCS05		XCS10		XCS20		XCS30		XCS40	
Max System Gates	5,000		10,000		20,000		30,000		40,000	
CLBs (Row x Col.)	100 (10 x 10)		196 (14 x 14)		400 (20 x 20)		576 (24 x 24)		784 (28 x 28)	
IOBs	80		112		160		192		205(4)	
Part Number	XCS05	XCS05XL	XCS10	XCS10XL	XCS20	XCS20XL	XCS30	XCS30XL	XCS40	XCS40XL
Supply Voltage	5V	3.3V	5V	3.3V	5V	3.3V	5V	3.3V	5V	3.3V
Bits per Frame	126	127	166	167	226	227	266	267	306	307
Frames	428	429	572	573	788	789	932	933	1,076	1,077
Program Data	53,936	54,491	94,960	95,699	178,096	179,111	247,920	249,119	329,264	330,647
PROM Size (bits)	53,984	54,544	95,008	95,752	178,144	179,160	247,968	249,168	329,312	330,696
Express Mode PROM Size (bits)	-	79,072	-	128,488	-	221,056	-	298,696	-	387,856

Notes:

1. Bits per Frame = (10 x number of rows) + 7 for the top + 13 for the bottom + 1 + 1 start bit + 4 error check bits (+1 for Spartan-XL device)
   Number of Frames = (36 x number of columns) + 26 for the left edge + 41 for the right edge + 1 (+ 1 for Spartan-XL device)
   Program Data = (Bits per Frame x Number of Frames) + 8 postamble bits
   PROM Size = Program Data + 40 (header) + 8, rounded up to the nearest byte
2. The user can add more "1" bits as leading dummy bits in the header, or, if CRC = off, as trailing dummy bits at the end of any frame, following the four error check bits. However, the Length Count value **must** be adjusted for all such extra "one" bits, even for extra leading ones at the beginning of the header.
3. Express mode adds 57 (XCS05XL, XCS10XL), or 53 (XCS20XL, XCS30XL, XCS40XL) bits per frame, + additional start-up bits.
4. XCS40XL provided 224 max I/O in CS280 package discontinued by PDN2004-01.

During Readback, 11 bits of the 16-bit checksum are added to the end of the Readback data stream. The checksum is computed using the CRC-16 CCITT polynomial, as shown in Figure 29. The checksum consists of the 11 most significant bits of the 16-bit code. A change in the checksum indicates a change in the Readback bitstream. A comparison to a previous checksum is meaningful only if the readback data is independent of the current device state. CLB outputs should not be included (Readback Capture option not used), and if RAM is present, the RAM content must be unchanged.

Statistically, one error out of 2048 might go undetected.

to wait after completing the configuration memory clear operation. When $\overline{INIT}$ is no longer held Low externally, the device determines its configuration mode by capturing the state of the Mode pins, and is ready to start the configuration process. A master device waits up to an additional 300 µs to make sure that any slaves in the optional daisy chain have seen that $\overline{INIT}$ is High.

For more details on Configuration, refer to the Xilinx Application Note "FPGA Configuration Guidelines" (XAPP090).

Start-Up

Start-up is the transition from the configuration process to the intended user operation. This transition involves a change from one clock source to another, and a change from interfacing parallel or serial configuration data where most outputs are 3-stated, to normal operation with I/O pins active in the user system. Start-up must make sure that the user logic 'wakes up' gracefully, that the outputs become active without causing contention with the configuration signals, and that the internal flip-flops are released from the Global Set/Reset (GSR) at the right time.

Start-Up Initiation

Two conditions have to be met in order for the start-up sequence to begin:

- The chip's internal memory must be full, and
- The configuration length count must be met, exactly.

In all configuration modes except Express mode, Spartan/XL devices read the expected length count from the bitstream and store it in an internal register. The length count varies according to the number of devices and the composition of the daisy chain. Each device also counts the number of CCLKs during configuration.

In Express mode, there is no length count. The start-up sequence for each device begins when the device has received its quota of configuration data. Wiring the DONE pins of several devices together delays start-up of all devices until all are fully configured.

Start-Up Events

The device can be programmed to control three start-up events.

- The release of the open-drain DONE output
- The termination of the Global Three-State and the change of configuration-related pins to the user function, activating all IOBs.
- The termination of the Global Set/Reset initialization of all CLB and IOB storage elements.

Figure 31 describes start-up timing in detail. The three events — DONE going High, the internal GSR being de-activated, and the user I/O going active — can all occur in any arbitrary sequence. This relative timing is selected by options in the bitstream generation software. Heavy lines in Figure 31 show the default timing. The thin lines indicate all other possible timing options. The start-up logic must be clocked until the "F" (Finished) state is reached.

The default option, and the most practical one, is for DONE to go High first, disconnecting the configuration data source and avoiding any contention when the I/Os become active one clock later. GSR is then released another clock period later to make sure that user operation starts from stable internal conditions. This is the most common sequence, shown with heavy lines in Figure 31, but the designer can modify it to meet particular requirements.

Start-Up Clock

Normally, the start-up sequence is controlled by the internal device oscillator (CCLK), which is asynchronous to the system clock. As a configuration option, they can be triggered by an on-chip user net called UCLK. This user net can be accessed by placing the STARTUP library symbol, and the start-up modes are known as UCLK_NOSYNC or UCLK_SYNC. This allows the device to wake up in synchronism with the user system.

DONE Pin

Note that DONE is an open-drain output and does not go High unless an internal pull-up is activated or an external pull-up is attached. The internal pull-up is activated as the default by the bitstream generation software.

The DONE pin can also be wire-ANDed with DONE pins of other FPGAs or with other external signals, and can then be used as input to the start-up control logic. This is called "Start-up Timing Synchronous to Done In" and is selected by either CCLK_SYNC or UCLK_SYNC. When DONE is not used as an input, the operation is called "Start-up Timing Not Synchronous to DONE In," and is selected by either CCLK_NOSYNC or UCLK_NOSYNC. Express mode configuration always uses either CCLK_SYNC or UCLK_SYNC timing, while the other configuration modes can use any of the four timing sequences.

When the UCLK_SYNC option is enabled, the user can externally hold the open-drain DONE output Low, and thus stall all further progress in the start-up sequence until DONE is released and has gone High. This option can be used to force synchronization of several FPGAs to a common user clock, or to guarantee that all devices are successfully configured before any I/Os go active.

Readback Switching Characteristics Guidelines

The following guidelines reflect worst-case values over the recommended operating conditions.

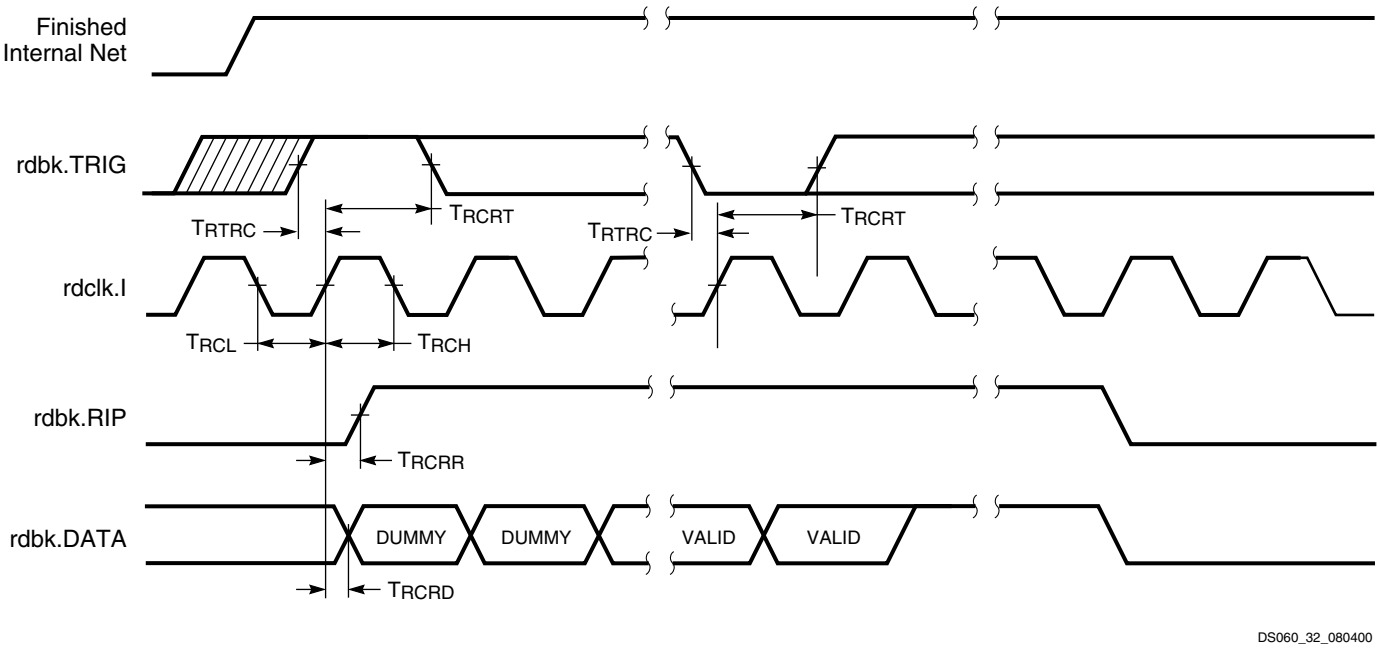


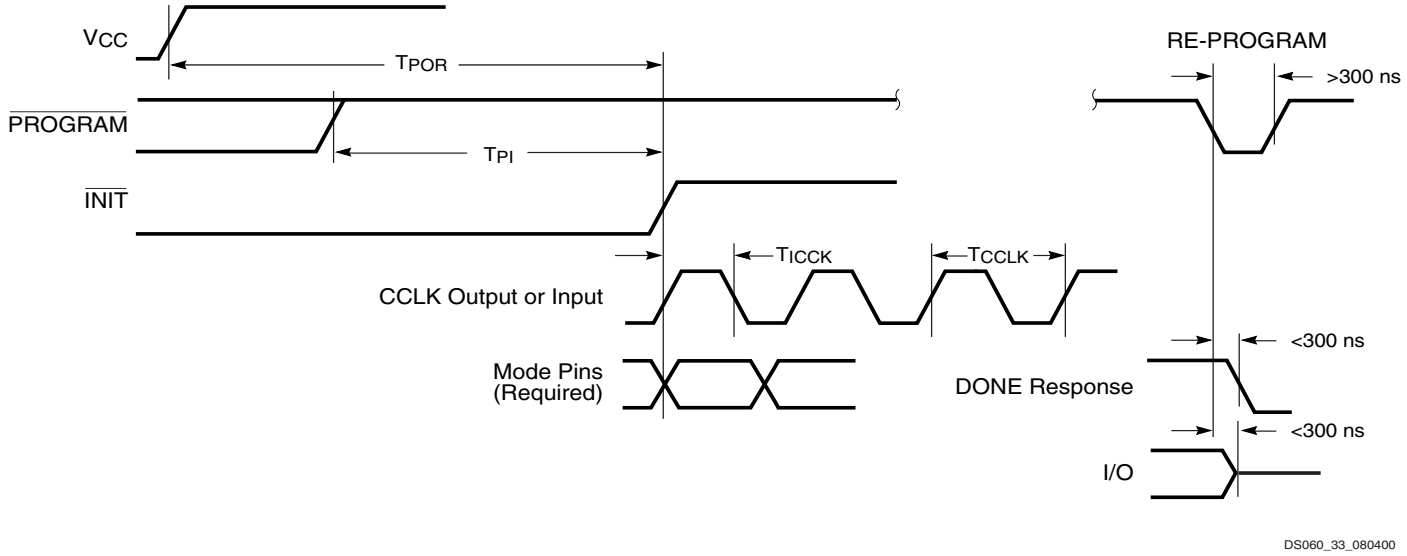
Figure 33: **Spartan and Spartan-XL Readback Timing Diagram**

Spartan and Spartan-XL Readback Switching Characteristics

Symbol		Description	Min	Max	Units
T_{RTRC}	rdbk.TRIG	rdbk.TRIG setup to initiate and abort Readback	200	-	ns
T_{RCRT}		rdbk.TRIG hold to initiate and abort Readback	50	-	ns
T_{RCRD}	rdclk.I	rdbk.DATA delay	-	250	ns
T_{RCRR}		rdbk.RIP delay	-	250	ns
T_{RCH}		High time	250	500	ns
T_{RCL}		Low time	250	500	ns

Notes:
1. Timing parameters apply to all speed grades.
2. If rdbk.TRIG is High prior to Finished, Finished will trigger the first Readback.

Configuration Switching Characteristics



Master Mode

Symbol	Description	Min	Max	Units
T_{POR}	Power-on reset	40	130	ms
T_{PI}	Program Latency	30	200	µs per CLB column
T_{ICCK}	CCLK (output) delay	40	250	µs
T_{CCLK}	CCLK (output) period, slow	640	2000	ns
T_{CCLK}	CCLK (output) period, fast	100	250	ns

Slave Mode

Symbol	Description	Min	Max	Units
T_{POR}	Power-on reset	10	33	ms
T_{PI}	Program latency	30	200	µs per CLB column
T_{ICCK}	CCLK (input) delay (required)	4	-	µs
T_{CCLK}	CCLK (input) period (required)	80	-	ns

Spartan Family CLB RAM Synchronous (Edge-Triggered) Write Operation Guidelines

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan devices and are expressed in nanoseconds unless otherwise noted.

Symbol	Single Port RAM	Size[1]	Speed Grade				Units
			-4		-3		
			Min	Max	Min	Max	
Write Operation							
T_{WCS}	Address write cycle time (clock K period)	16x2	8.0	-	11.6	-	ns
T_{WCTS}		32x1	8.0	-	11.6	-	ns
T_{WPS}	Clock K pulse width (active edge)	16x2	4.0	-	5.8	-	ns
T_{WPTS}		32x1	4.0	-	5.8	-	ns
T_{ASS}	Address setup time before clock K	16x2	1.5	-	2.0	-	ns
T_{ASTS}		32x1	1.5	-	2.0	-	ns
T_{AHS}	Address hold time after clock K	16x2	0.0	-	0.0	-	ns
T_{AHTS}		32x1	0.0	-	0.0	-	ns
T_{DSS}	DIN setup time before clock K	16x2	1.5	-	2.7	-	ns
T_{DSTS}		32x1	1.5	-	1.7	-	ns
T_{DHS}	DIN hold time after clock K	16x2	0.0	-	0.0	-	ns
T_{DHTS}		32x1	0.0	-	0.0	-	ns
T_{WSS}	WE setup time before clock K	16x2	1.5	-	1.6	-	ns
T_{WSTS}		32x1	1.5	-	1.6	-	ns
T_{WHS}	WE hold time after clock K	16x2	0.0	-	0.0	-	ns
T_{WHTS}		32x1	0.0	-	0.0	-	ns
T_{WOS}	Data valid after clock K	16x2	-	6.5	-	7.9	ns
T_{WOTS}		32x1	-	7.0	-	9.3	ns
Read Operation							
T_{RC}	Address read cycle time	16x2	2.6	-	2.6	-	ns
T_{RCT}		32x1	3.8	-	3.8	-	ns
T_{ILO}	Data valid after address change (no Write Enable)	16x2	-	1.2	-	1.6	ns
T_{IHO}		32x1	-	2.0	-	2.7	ns
T_{ICK}	Address setup time before clock K	16x2	1.8	-	2.4	-	ns
T_{IHCK}		32x1	2.9	-	3.9	-	ns

Notes:
1. Timing for 16 x 1 RAM option is identical to 16 x 2 RAM timing.

Spartan Family CLB RAM Synchronous (Edge-Triggered) Write Operation Guidelines (continued)

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan devices and are expressed in nanoseconds unless otherwise noted.

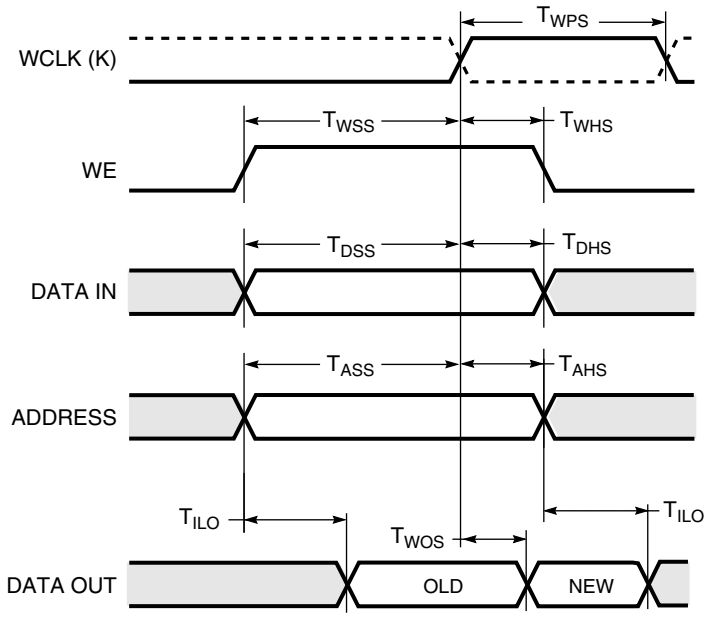
Dual-Port RAM Synchronous (Edge-Triggered) Write Operation Characteristics

Symbol	Dual Port RAM	Size[1]	-4		-3		Units
			Min	Max	Min	Max	
Write Operation							
T_{WCDS}	Address write cycle time (clock K period)	16x1	8.0	-	11.6	-	ns
T_{WPDS}	Clock K pulse width (active edge)	16x1	4.0	-	5.8	-	ns
T_{ASDS}	Address setup time before clock K	16x1	1.5	-	2.1	-	ns
T_{AHDS}	Address hold time after clock K	16x1	0	-	0	-	ns
T_{DSDS}	DIN setup time before clock K	16x1	1.5	-	1.6	-	ns
T_{DHDS}	DIN hold time after clock K	16x1	0	-	0	-	ns
T_{WSDS}	WE setup time before clock K	16x1	1.5	-	1.6	-	ns
T_{WHDS}	WE hold time after clock K	16x1	0	-	0	-	ns
T_{WODS}	Data valid after clock K	16x1	-	6.5	-	7.0	ns

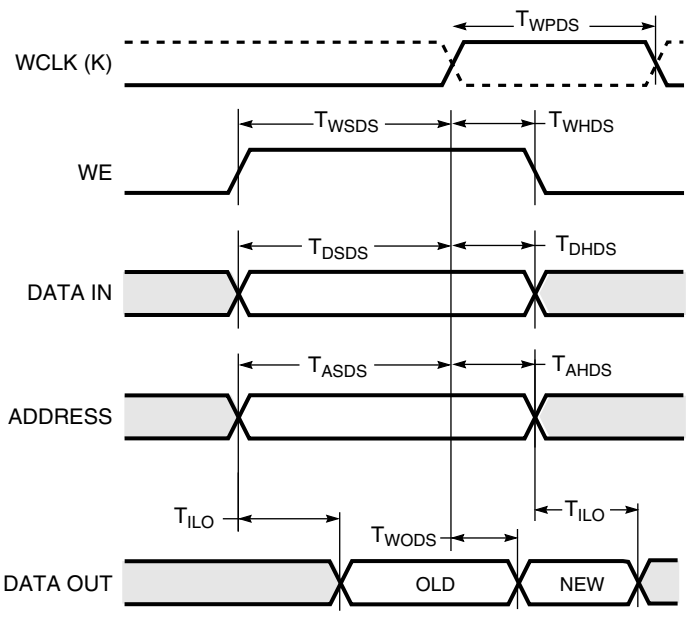
Notes:
1. Read Operation timing for 16 x 1 dual-port RAM option is identical to 16 x 2 single-port RAM timing

Spartan Family CLB RAM Synchronous (Edge-Triggered) Write Timing

Single Port



Dual Port



DS060_34_011300

Table 18: **Pin Descriptions *(Continued)***

Pin Name	I/O During Config.	I/O After Config.	Pin Description
$\overline{\text{PWRDWN}}$	I	I	$\overline{\text{PWRDWN}}$ is an active Low input that forces the FPGA into the Power Down state and reduces power consumption. When $\overline{\text{PWRDWN}}$ is Low, the FPGA disables all I/O and initializes all flip-flops. All inputs are interpreted as Low independent of their actual level. VCC must be maintained, and the configuration data is maintained. $\overline{\text{PWRDWN}}$ halts configuration if asserted before or during configuration, and re-starts configuration when removed. When $\overline{\text{PWRDWN}}$ returns High, the FPGA becomes operational by first enabling the inputs and flip-flops and then enabling the outputs. $\overline{\text{PWRDWN}}$ has a default internal pull-up resistor.
User I/O Pins That Can Have Special Functions			
TDO	O	O	If boundary scan is used, this pin is the Test Data Output. If boundary scan is not used, this pin is a 3-state output without a register, after configuration is completed. To use this pin, place the library component TDO instead of the usual pad symbol. An output buffer must still be used.
TDI, TCK, TMS	I	I/O or I (JTAG)	If boundary scan is used, these pins are Test Data In, Test Clock, and Test Mode Select inputs respectively. They come directly from the pads, bypassing the IOBs. These pins can also be used as inputs to the CLB logic after configuration is completed. If the BSCAN symbol is not placed in the design, all boundary scan functions are inhibited once configuration is completed, and these pins become user-programmable I/O. In this case, they must be called out by special library elements. To use these pins, place the library components TDI, TCK, and TMS instead of the usual pad symbols. Input or output buffers must still be used.
HDC	O	I/O	High During Configuration (HDC) is driven High until the I/O go active. It is available as a control output indicating that configuration is not yet completed. After configuration, HDC is a user-programmable I/O pin.
$\overline{\text{LDC}}$	O	I/O	Low During Configuration ($\overline{\text{LDC}}$) is driven Low until the I/O go active. It is available as a control output indicating that configuration is not yet completed. After configuration, $\overline{\text{LDC}}$ is a user-programmable I/O pin.
$\overline{\text{INIT}}$	I/O	I/O	Before and during configuration, $\overline{\text{INIT}}$ is a bidirectional signal. A 1 kΩ to 10 kΩ external pull-up resistor is recommended. As an active Low open-drain output, $\overline{\text{INIT}}$ is held Low during the power stabilization and internal clearing of the configuration memory. As an active Low input, it can be used to hold the FPGA in the internal WAIT state before the start of configuration. Master mode devices stay in a WAIT state an additional 30 to 300 µs after $\overline{\text{INIT}}$ has gone High. During configuration, a Low on this output indicates that a configuration data error has occurred. After the I/O go active, $\overline{\text{INIT}}$ is a user-programmable I/O pin.
PGCK1 - PGCK4 (Spartan)	Weak Pull-up	I or I/O	Four Primary Global inputs each drive a dedicated internal global net with short delay and minimal skew. If not used to drive a global buffer, any of these pins is a user-programmable I/O. The PGCK1-PGCK4 pins drive the four Primary Global Buffers. Any input pad symbol connected directly to the input of a BUFGP symbol is automatically placed on one of these pins.

Table 18: **Pin Descriptions *(Continued)***

Pin Name	I/O During Config.	I/O After Config.	Pin Description
SGCK1 - SGCK4 (Spartan)	Weak Pull-up (except SGCK4 is DOUT)	I or I/O	Four Secondary Global inputs each drive a dedicated internal global net with short delay and minimal skew. These internal global nets can also be driven from internal logic. If not used to drive a global net, any of these pins is a user-programmable I/O pin. The SGCK1-SGCK4 pins provide the shortest path to the four Secondary Global Buffers. Any input pad symbol connected directly to the input of a BUFGS symbol is automatically placed on one of these pins.
GCK1 - GCK8 (Spartan-XL)	Weak Pull-up (except GCK6 is DOUT)	I or I/O	Eight Global inputs each drive a dedicated internal global net with short delay and minimal skew. These internal global nets can also be driven from internal logic. If not used to drive a global net, any of these pins is a user-programmable I/O pin. The GCK1-GCK8 pins provide the shortest path to the eight Global Low-Skew Buffers. Any input pad symbol connected directly to the input of a BUFGLS symbol is automatically placed on one of these pins.
CS1 (Spartan-XL)	I	I/O	During Express configuration, CS1 is used as a serial-enable signal for daisy-chaining.
D0-D7 (Spartan-XL)	I	I/O	During Express configuration, these eight input pins receive configuration data. After configuration, they are user-programmable I/O pins.
DIN	I	I/O	During Slave Serial or Master Serial configuration, DIN is the serial configuration data input receiving data on the rising edge of CCLK. After configuration, DIN is a user-programmable I/O pin.
DOUT	O	I/O	During Slave Serial or Master Serial configuration, DOUT is the serial configuration data output that can drive the DIN of daisy-chained slave FPGAs. DOUT data changes on the falling edge of CCLK, one-and-a-half CCLK periods after it was received at the DIN input. In Spartan-XL family Express mode, DOUT is the status output that can drive the CS1 of daisy-chained FPGAs, to enable and disable downstream devices. After configuration, DOUT is a user-programmable I/O pin.
Unrestricted User-Programmable I/O Pins			
I/O	Weak Pull-up	I/O	These pins can be configured to be input and/or output after configuration is completed. Before configuration is completed, these pins have an internal high-value pull-up resistor network that defines the logic level as High.

Device-Specific Pinout Tables

Device-specific tables include all packages for each Spartan and Spartan-XL device. They follow the pad locations around the die, and include boundary scan register locations.

Some Spartan-XL devices are available in Pb-free package options. The Pb-free package options have the same pinouts as the standard package options.

XCS05 and XCS05XL Device Pinouts

XCS05/XL Pad Name	PC84(4)	VQ100	Bndry Scan
VCC	P2	P89	-
I/O	P3	P90	32
I/O	P4	P91	35
I/O	-	P92	38
I/O	-	P93	41
I/O	P5	P94	44
I/O	P6	P95	47
I/O	P7	P96	50
I/O	P8	P97	53
I/O	P9	P98	56
I/O, SGCK1(1), GCK8(2)	P10	P99	59
VCC	P11	P100	-
GND	P12	P1	-
I/O, PGCK1(1), GCK1(2)	P13	P2	62
I/O	P14	P3	65
I/O, TDI	P15	P4	68
I/O, TCK	P16	P5	71
I/O, TMS	P17	P6	74
I/O	P18	P7	77
I/O	-	P8	83
I/O	P19	P9	86
I/O	P20	P10	89
GND	P21	P11	-
VCC	P22	P12	-
I/O	P23	P13	92
I/O	P24	P14	95
I/O	-	P15	98
I/O	P25	P16	104
I/O	P26	P17	107
I/O	P27	P18	110
I/O	-	P19	113
I/O	P28	P20	116
I/O, SGCK2(1), GCK2(2)	P29	P21	119
Not Connected(1), M1(2)	P30	P22	122
GND	P31	P23	-
MODE(1), M0 (2)	P32	P24	125
VCC	P33	P25	-

XCS05 and XCS05XL Device Pinouts

XCS05/XL Pad Name	PC84(4)	VQ100	Bndry Scan
Not Connected(1), $\overline{\text{PWRDWN}}$(2)	P34	P26	126(1)
I/O, PGCK2(1), GCK3 (2)	P35	P27	127(3)
I/O (HDC)	P36	P28	130(3)
I/O	-	P29	133(3)
I/O ($\overline{\text{LDC}}$)	P37	P30	136(3)
I/O	P38	P31	139(3)
I/O	P39	P32	142(3)
I/O	-	P33	145(3)
I/O	-	P34	148(3)
I/O	P40	P35	151(3)
I/O ($\overline{\text{INIT}}$)	P41	P36	154(3)
VCC	P42	P37	-
GND	P43	P38	-
I/O	P44	P39	157(3)
I/O	P45	P40	160(3)
I/O	-	P41	163(3)
I/O	-	P42	166(3)
I/O	P46	P43	169(3)
I/O	P47	P44	172(3)
I/O	P48	P45	175(3)
I/O	P49	P46	178(3)
I/O	P50	P47	181(3)
I/O, SGCK3(1), GCK4(2)	P51	P48	184(3)
GND	P52	P49	-
DONE	P53	P50	-
VCC	P54	P51	-
$\overline{\text{PROGRAM}}$	P55	P52	-
I/O (D7(2))	P56	P53	187(3)
I/O, PGCK3(1), GCK5(2)	P57	P54	190(3)
I/O (D6(2))	P58	P55	193(3)
I/O	-	P56	196(3)
I/O (D5(2))	P59	P57	199(3)
I/O	P60	P58	202(3)
I/O	-	P59	205(3)
I/O	-	P60	208(3)
I/O (D4(2))	P61	P61	211(3)
I/O	P62	P62	214(3)
VCC	P63	P63	-
GND	P64	P64	-
I/O (D3(2))	P65	P65	217(3)
I/O	P66	P66	220(3)
I/O	-	P67	223(3)
I/O (D2(2))	P67	P68	229(3)
I/O	P68	P69	232(3)
I/O (D1(2))	P69	P70	235(3)

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84[4]	VQ100	CS144[2,4]	TQ144	Bndry Scan
VCC	P33	P25	N1	P37	-
Not Connect-ed[1] PWRDWN[2]	P34	P26	N2	P38	174 [1]
I/O, PGCK2[1] GCK3[2]	P35	P27	M3	P39	175[3]
I/O (HDC)	P36	P28	N3	P40	178 [3]
I/O	-	-	K4	P41	181 [3]
I/O	-	-	L4	P42	184 [3]
I/O	-	P29	M4	P43	187 [3]
I/O ($\overline{LDC}$)	P37	P30	N4	P44	190 [3]
GND	-	-	K5	P45	-
I/O	-	-	L5	P46	193 [3]
I/O	-	-	M5	P47	196 [3]
I/O	P38	P31	N5	P48	199 [3]
I/O	P39	P32	K6	P49	202 [3]
I/O	-	P33	L6	P50	205 [3]
I/O	-	P34	M6	P51	208 [3]
I/O	P40	P35	N6	P52	211 [3]
I/O ($\overline{INIT}$)	P41	P36	M7	P53	214 [3]
VCC	P42	P37	N7	P54	-
GND	P43	P38	L7	P55	-
I/O	P44	P39	K7	P56	217 [3]
I/O	P45	P40	N8	P57	220 [3]
I/O	-	P41	M8	P58	223 [3]
I/O	-	P42	L8	P59	226 [3]
I/O	P46	P43	K8	P60	229 [3]
I/O	P47	P44	N9	P61	232 [3]
I/O	-	-	M9	P62	235 [3]
I/O	-	-	L9	P63	238 [3]
GND	-	-	K9	P64	-
I/O	P48	P45	N10	P65	241 [3]
I/O	P49	P46	M10	P66	244 [3]
I/O	-	-	L10	P67	247 [3]
I/O	-	-	N11	P68	250 [3]
I/O	P50	P47	M11	P69	253 [3]
I/O, SGCK3[1] GCK4[2]	P51	P48	L11	P70	256 [3]
GND	P52	P49	N12	P71	-
DONE	P53	P50	M12	P72	-
VCC	P54	P51	N13	P73	-
$\overline{PROGRAM}$	P55	P52	M13	P74	-
I/O (D7[2])	P56	P53	L12	P75	259 [3]

XCS10 and XCS10XL Device Pinouts

XCS10/XL Pad Name	PC84[4]	VQ100	CS144[2,4]	TQ144	Bndry Scan
I/O, PGCK3[1] GCK5[2]	P57	P54	L13	P76	262 [3]
I/O	-	-	K10	P77	265 [3]
I/O	-	-	K11	P78	268 [3]
I/O (D6[2])	P58	P55	K12	P79	271 [3]
I/O	-	P56	K13	P80	274 [3]
GND	-	-	J10	P81	-
I/O	-	-	J11	P82	277 [3]
I/O	-	-	J12	P83	280 [3]
I/O (D5[2])	P59	P57	J13	P84	283 [3]
I/O	P60	P58	H10	P85	286 [3]
I/O	-	P59	H11	P86	289 [3]
I/O	-	P60	H12	P87	292 [3]
I/O (D4[2])	P61	P61	H13	P88	295 [3]
I/O	P62	P62	G12	P89	298 [3]
VCC	P63	P63	G13	P90	-
GND	P64	P64	G11	P91	-
I/O (D3[2])	P65	P65	G10	P92	301 [3]
I/O	P66	P66	F13	P93	304 [3]
I/O	-	P67	F12	P94	307 [3]
I/O	-	-	F11	P95	310 [3]
I/O (D2[2])	P67	P68	F10	P96	313 [3]
I/O	P68	P69	E13	P97	316 [3]
I/O	-	-	E12	P98	319 [3]
I/O	-	-	E11	P99	322 [3]
GND	-	-	E10	P100	-
I/O (D1[2])	P69	P70	D13	P101	325 [3]
I/O	P70	P71	D12	P102	328 [3]
I/O	-	-	D11	P103	331 [3]
I/O	-	-	C13	P104	334 [3]
I/O (D0[2], DIN)	P71	P72	C12	P105	337 [3]
I/O, SGCK4[1] GCK6[2] (DOUT)	P72	P73	C11	P106	340 [3]
CCLK	P73	P74	B13	P107	-
VCC	P74	P75	B12	P108	-
O, TDO	P75	P76	A13	P109	0
GND	P76	P77	A12	P110	-
I/O	P77	P78	B11	P111	2
I/O, PGCK4[1] GCK7[2]	P78	P79	A11	P112	5
I/O	-	-	D10	P113	8
I/O	-	-	C10	P114	11
I/O (CS1[2])	P79	P80	B10	P115	14

Additional XCS20/XL Package Pins

PQ208					
Not Connected Pins					
P12	P18 (1)	P33 (1)	P39	P65	P71 (1)
P86 (1)	P92	P111	P121(1)	P140(1)	P144
P165	P173(1)	P192(1)	P202	P203	-
9/16/98					

Notes:
1. 5V Spartan family only
2. 3V Spartan-XL family only
3. The “PWRDWN” on the XCS20XL is not part of the Boundary Scan chain. For the XCS20XL, subtract 1 from all Boundary Scan numbers from GCK3 on (247 and higher).
4. CS144 package discontinued by PDN2004-01

XCS30 and XCS30XL Device Pinouts

XCS30/XL Pad Name	VQ100(5)	TQ144	PQ208	PQ240	BG256(5)	CS280(2,5)	Bndry Scan
VCC	P89	P128	P183	P212	VCC(4)	C10	-
I/O	P90	P129	P184	P213	C10	D10	74
I/O	P91	P130	P185	P214	D10	E10	77
I/O	P92	P131	P186	P215	A9	A9	80
I/O	P93	P132	P187	P216	B9	B9	83
I/O	-	-	P188	P217	C9	C9	86
I/O	-	-	P189	P218	D9	D9	89
I/O	P94	P133	P190	P220	A8	A8	92
I/O	P95	P134	P191	P221	B8	B8	95
VCC	-	-	P192	P222	VCC(4)	A7	-
I/O	-	-	-	P223	A6	B7	98
I/O	-	-	-	P224	C7	C7	101
I/O	-	P135	P193	P225	B6	D7	104
I/O	-	P136	P194	P226	A5	A6	107
GND	-	P137	P195	P227	GND(4)	GND(4)	-
I/O	-	-	P196	P228	C6	B6	110
I/O	-	-	P197	P229	B5	C6	113
I/O	-	-	P198	P230	A4	D6	116
I/O	-	-	P199	P231	C5	E6	119
I/O	P96	P138	P200	P232	B4	A5	122
I/O	P97	P139	P201	P233	A3	C5	125
I/O	-	-	P202	P234	D5	B4	128
I/O	-	-	P203	P235	C4	C4	131
I/O	-	P140	P204	P236	B3	A3	134
I/O	-	P141	P205	P237	B2	A2	137
I/O	P98	P142	P206	P238	A2	B3	140
I/O, SGCK1(1), GCK8(2)	P99	P143	P207	P239	C3	B2	143
VCC	P100	P144	P208	P240	VCC(4)	A1	-
GND	P1	P1	P1	P1	GND(4)	GND(4)	-
I/O, PGCK1(1), GCK1(2)	P2	P2	P2	P2	B1	C3	146
I/O	P3	P3	P3	P3	C2	C2	149
I/O	-	P4	P4	P4	D2	B1	152

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280(2,5)	Bndry Scan
GND	P25	P29	GND(4)	GND(4)	-
VCC	P26	P30	VCC(4)	VCC(4)	-
I/O	P27	P31	L2	K3	254
I/O	P28	P32	L3	K4	257
I/O	P29	P33	L4	K5	260
I/O	P30	P34	M1	L1	263
I/O	P31	P35	M2	L2	266
I/O	P32	P36	M3	L3	269
I/O	-	-	M4	L4	272
I/O	-	-	-	M1	275
I/O	-	P38	N1	M2	278
I/O	-	P39	N2	M3	281
VCC	P33	P40	VCC(4)	VCC(4)	-
I/O	P34	P41	P1	N1	284
I/O	P35	P42	P2	N2	287
I/O	P36	P43	R1	N3	290
I/O	P37	P44	P3	N4	293
GND	P38	P45	GND(4)	GND(4)	-
I/O	-	P46	T1	P1	296
I/O	P39	P47	R3	P2	299
I/O	P40	P48	T2	P3	302
I/O	P41	P49	U1	P4	305
I/O	P42	P50	T3	P5	308
I/O	P43	P51	U2	R1	311
I/O	-	-	-	R2	314
I/O	-	-	-	R4	317
I/O	P44	P52	V1	T1	320
I/O	P45	P53	T4	T2	323
I/O	P46	P54	U3	T3	326
I/O	P47	P55	V2	U1	329
I/O	P48	P56	W1	V1	332
I/O, SGCK2(1), GCK2 (2)	P49	P57	V3	U2	335
Not Connected(1) M1(2)	P50	P58	W2	V2	338
GND	P51	P59	GND(4)	GND(4)	-
MODE(1), M0(2)	P52	P60	Y1	W1	341
VCC	P53	P61	VCC(4)	VCC(4)	-
Not Connected(1) $\overline{\text{PWRDWN}}$(2)	P54	P62	W3	V3	342(1)
I/O, PGCK2(1), GCK3(2)	P55	P63	Y2	W2	343 (3)

XCS40 and XCS40XL Device Pinouts

XCS40/XL Pad Name	PQ208	PQ240	BG256	CS280(2,5)	Bndry Scan
I/O (HDC)	P56	P64	W4	W3	346 (3)
I/O	P57	P65	V4	T4	349 (3)
I/O	P58	P66	U5	U4	352 (3)
I/O	P59	P67	Y3	V4	355 (3)
I/O ($\overline{\text{LDC}}$)	P60	P68	Y4	W4	358 (3)
I/O	-	-	-	R5	361 (3)
I/O	-	-	-	U5	364 (3)
I/O	P61	P69	V5	T5	367 (3)
I/O	P62	P70	W5	W5	370 (3)
I/O	P63	P71	Y5	R6	373 (3)
I/O	P64	P72	V6	U6	376 (3)
I/O	P65	P73	W6	V6	379 (3)
I/O	-	P74	Y6	T6	382 (3)
GND	P66	P75	GND(4)	GND(4)	-
I/O	P67	P76	W7	W6	385 (3)
I/O	P68	P77	Y7	U7	388 (3)
I/O	P69	P78	V8	V7	391 (3)
I/O	P70	P79	W8	W7	394 (3)
VCC	P71	P80	VCC(4)	VCC(4)	-
I/O	P72	P81	Y8	W8	397 (3)
I/O	P73	P82	U9	U8	400 (3)
I/O	-	-	V9	V8	403 (3)
I/O	-	-	W9	T8	406 (3)
I/O	-	P84	Y9	W9	409 (3)
I/O	-	P85	W10	V9	412 (3)
I/O	P74	P86	V10	U9	415 (3)
I/O	P75	P87	Y10	T9	418 (3)
I/O	P76	P88	Y11	W10	421 (3)
I/O ($\overline{\text{INIT}}$)	P77	P89	W11	V10	424 (3)
VCC	P78	P90	VCC(4)	VCC(4)	VCC(4)
GND	P79	P91	GND(4)	GND(4)	-
I/O	P80	P92	V11	T10	427 (3)
I/O	P81	P93	U11	R10	430 (3)
I/O	P82	P94	Y12	W11	433 (3)
I/O	P83	P95	W12	V11	436 (3)
I/O	P84	P96	V12	U11	439 (3)
I/O	P85	P97	U12	T11	442 (3)
I/O	-	-	Y13	W12	445 (3)
I/O	-	-	W13	V12	448 (3)
I/O	-	P99	V13	U12	451 (3)
I/O	-	P100	Y14	T12	454 (3)
VCC	P86	P101	VCC(4)	VCC(4)	-
I/O	P87	P102	Y15	V13	457 (3)
I/O	P88	P103	V14	U13	460 (3)
I/O	P89	P104	W15	T13	463 (3)

Table 20: **User I/O Chart for Spartan/XL FPGAs**

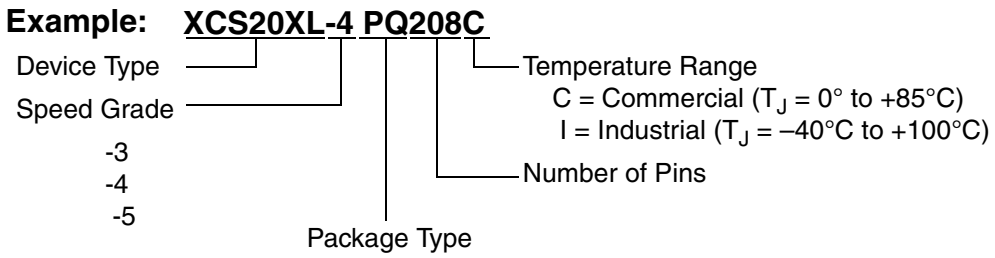
Device	Max I/O	Package Type							
		PC84(1)	VQ100(1)	CS144(1)	TQ144	PQ208	PQ240	BG256(1)	CS280(1)
XCS05	80	61(1)	77	-	-	-	-	-	-
XCS10	112	61(1)	77	-	112	-	-	-	-
XCS20	160	-	77	-	113	160	-	-	-
XCS30	192	-	77(1)	-	113	169	192	192(1)	-
XCS40	224	-	-	-	-	169	192	205	-
XCS05XL	80	61(1)	77(2)	-	-	-	-	-	-
XCS10XL	112	61(1)	77(2)	112(1)	112(2)	-	-	-	-
XCS20XL	160	-	77(2)	113(1)	113(2)	160(2)	-	-	-
XCS30XL	192	-	77(2)	-	113(2)	169(2)	192(2)	192(2)	192(1)
XCS40XL	224	-	-	-	-	169(2)	192(2)	205(2)	224(1)

6/25/08

Notes:

1. PC84, CS144, and CS280 packages, and VQ100 and BG256 packages for XCS30 only, discontinued by PDN2004-01
2. These Spartan-XL devices are available in Pb-free package options. The Pb-free packages insert a "G" in the package code. Contact Xilinx for availability.

Ordering Information



BG = Ball Grid Array
BGG = Ball Grid Array (Pb-free)
PC = Plastic Lead Chip Carrier
PQ = Plastic Quad Flat Pack
PQG = Plastic Quad Flat Pack (Pb-free)
VQ = Very Thin Quad Flat Pack
VQG = Very Thin Quad Flat Pack (Pb-free)
TQ = Thin Quad Flat Pack
TQG = Thin Quad Flat Pack (Pb-free)
CS = Chip Scale

Revision History

The following table shows the revision history for this document.

Date	Version	Description
11/20/98	1.3	Added Spartan-XL specs and Power Down.
01/06/99	1.4	All Spartan-XL -4 specs designated Preliminary with no changes.
03/02/00	1.5	Added CS package, updated Spartan-XL specs to Final.
09/19/01	1.6	Reformatted, updated power specs, clarified configuration information. Removed T_{SOL} soldering information from Absolute Maximum Ratings table. Changed Figure 26: Slave Serial Mode Characteristics: T_{CCH}, T_{CCL} from 45 to 40 ns. Changed Master Mode Configuration Switching Characteristics: T_{CCLK} min. from 80 to 100 ns. Added Total Dist. RAM Bits to Table 1; added **Start-Up**, page 36 characteristics.
06/27/02	1.7	Clarified Express Mode pseudo daisy chain. Added new Industrial options. Clarified XCS30XL CS280 V_{CC} pinout.
06/26/08	1.8	Noted that PC84, CS144, and CS280 packages, and VQ100 and BG256 packages for XCS30 only, are discontinued by **PDN2004-01**. Extended description of recommended maximum delay of reconfiguration in **Delaying Configuration After Power-Up**, page 35. Added reference to Pb-free package options and provided link to **Package Specifications**, page 81. Updated links.
03/01/13	2.0	The products listed in this data sheet are obsolete. See **XCN10016** and **XCN11010** for further information.